

用途:用于高效 DC/DC 转换和功率开关。

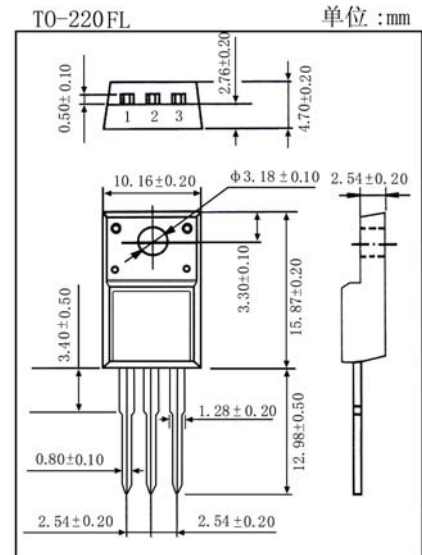
Purpose: These devices are well suited for high efficiency switching DC/DC converters and switch mode power supplies.

特点: 低栅电荷, 低反馈电容, 开关速度快。

Features: Low gate charge, low crss, fast switching.

极限参数/Absolute maximum ratings(Ta=25°C)

| 参数符号<br>Symbol   | 数值<br>Rating | 单位<br>Unit |
|------------------|--------------|------------|
| $V_{DSS}$        | 650          | V          |
| $I_D$ (Tc=25°C)  | 7.5          | A          |
| $I_D$ (Tc=100°C) | 4.6          | A          |
| $I_{DM}$         | 30           | A          |
| $V_{GSS}$        | ±30          | V          |
| $E_{AS}$         | 230          | mJ         |
| $E_{AR}$         | 10           | mJ         |
| $I_{AR}$         | 7.5          | A          |
| $P_D$ (Tc=25°C)  | 48           | W          |
| $T_J, T_{STG}$   | -55 to 150   | °C         |



引脚: 1.G 2.D 3.S

电性能参数/Electrical Characteristics(Ta=25°C)

| 参数符号<br>Symbol | 测试条件<br>Test Conditions                 | 最小值<br>Min | 典型值<br>Typ | 最大值<br>Max | 单位<br>Unit |
|----------------|-----------------------------------------|------------|------------|------------|------------|
| $BV_{DSS}$     | $V_{GS}=0V$ $I_D=250\mu A$              | 650        |            |            | V          |
| $I_{DSS}$      | $V_{DS}=650V$ $V_{GS}=0V$               |            |            | 1.0        | $\mu A$    |
|                | $V_{DS}=480V$ $T_C=125^\circ C$         |            |            | 10         | $\mu A$    |
| $I_{GSS}$      | $V_{GS}=\pm 30V$ $V_{DS}=0V$            |            |            | ±0.1       | $\mu A$    |
| $V_{GS(th)}$   | $V_{DS}=V_{GS}$ $I_D=250\mu A$          | 2.0        |            | 4.0        | V          |
| $R_{DS(on)}$   | $V_{GS}=10V$ $I_D=3.75A$                |            | 1.0        | 1.4        | $\Omega$   |
| $g_{FS}$       | $V_{DS}=40V$ $I_D=3.75A$                |            | 8.7        |            | S          |
| $V_{SD}$       | $V_{GS}=0V$ $I_S=7.5A$                  |            |            | 1.4        | V          |
| $C_{iss}$      | $V_{DS}=25V$ $V_{GS}=0V$ $f=1.0MHz$     |            | 965        | 1255       | pF         |
| $C_{oss}$      |                                         |            | 105        | 135        |            |
| $C_{rss}$      |                                         |            | 12         | 16         |            |
| $t_{d(on)}$    | $V_{DD}=300V$ $I_D=7.5A$ $R_G=25\Omega$ |            | 16.5       | 45         | ns         |
| $t_r$          |                                         |            | 60.5       | 130        |            |
| $t_{d(off)}$   |                                         |            | 81         | 170        |            |
| $t_f$          |                                         |            | 64.5       | 140        |            |

# BRF8N65 (CS8N65F)

